**Detailed Curriculum Vitae**

Prof. Dr. Sefer Bora Lisesivdin,   
 BSc (Engineering), MSc, PhD, SMIEEE

[[](https://orcid.org/0000-0001-9635-6770) https://orcid.org/0000-0001-9635-6770](# https://orcid.org/0000-0001-9635-6770)

**CONTACT INFORMATION**

(1) Department of Physics

Gazi University, Ankara, Turkey 06500

Phone: +90 312 202 1391

Email: [bora@gazi.edu.tr](mailto:bora@gazi.edu.tr), [sblisesivdin@gmail.com](mailto:sblisesivdin@gmail.com)

Personal web: [http://sblisesivdin.github.io](http://sblisesivdin.github.io/)

Group web: [http://www.lrgresearch.org](http://www.lrgresearch.org/)

**EDUCATION**

2008 Ph.D. Physics, Gazi University, Ankara, Turkey  
Dissertation: Electron and Magneto Transport Properties of AlGaN/GaN Based High Electron Mobility Transistors (HEMTs)  
Advisor: Prof. Dr. Mehmet Kasap

2005 M.Sc. Advanced Technologies, Gazi University, Ankara, Turkey

Thesis: Transport Properties of InGaAs/GaAs and AlGaAs/GaAs Semiconductors Grown by MBE

Advisor: Assoc. Prof. Dr. Mehmet Kasap

2002 B.Sc (Eng). Physics Engineering, Hacettepe University, Ankara Turkey

Senior Project: Development of X-Ray Data Analysis Software for Windows Systems

**RESEARCH INTERESTS**

Experimental and numerical (with calculating self-consistent solutions of Schroedinger-Poisson equations) investigation of electron and magnetotransport properties, strain, persistent photoconductivity, hot-electron transport properties, Shubnikov de Hass parameters and quantum parameters of 2 dimensional gas (2DEG) of III-V group semiconductor materials including, GaAs, GaN, InGaN, TiO2 bulks and AlGaN/GaN, AlGaN/(AlN)/GaN, AlGaN/(AlN)/GaN/AlN, AlInN/AlN/GaN/AlN and AlInN/AlN/InGaN/AlN heterostructures, MgZnO/ZnO, BeZnO/ZnO heterostructures.

Ab initio calculations of wide band gap semiconductors MgO, GaN, MgZnO, diamond and low dimensional structures like graphene, graphene nanoribbons, black phosphorus, 2D structures with kagome lattice structure.

Optical properties and ODMR measurements of NV- centers in Diamond.

**SCHOLARSHIPS / FELLOWSHIPS / AWARDS**

**2019 Leaders in Innovation Fellowship, Royal Academy of Engineering, United Kingdom,**

2017 Duty Award, Gazi University Faculty of Science, Ankara, Turkey.

**2016 Turkish Academy of Sciences, Distinguished Young Scientist Award**

**2015** **IEEE Senior Membership**

2015 SCI-indexed Publication Award, Gazi University, Ankara, Turkey.

2015 Duty Award, Gazi University Faculty of Science, Ankara, Turkey.

**2014** **Turkish Physical Union Prof. Dr. Sevket Erk Outstanding Young Scientist Award**.

2014 SCI-indexed Publication Award, Gazi University, Ankara, Turkey.

2014 SCI-indexed Citation Award, Gazi University, Ankara, Turkey.

2013 TUBITAK 2219 scholarship for postdoc research (6 months).

2007-present 20 publications are promoted through TUBITAK Incentive Program for International Scientific Publications.

2010, 2012 SCI-indexed Publication Award, Gazi University, Ankara, Turkey.

2008-2009 Postdoc fellowship for postdoc studies.

2007-2008 TUBITAK 2214 scholarship for PhD research (6 months).

2007 Progetto Lagrange PhD Scholarship, Politechnico di Torino, Italy (not used due to family issues).

2005-2008 Several project scholarship for M.Sc. and Ph.D. studies.

**GRANTS & PROJECT MEMBERSHIPS**

*Earned grants as a project investigator (PI) or project co-investigator (co-PI)*

2018-2019 TUBITAK 1512, 2180227, Production of Compact USB Fiber-coupled UV-VIS-NIR Optical Spectrometer for Industrial and Scientific Purposes, CEO and PI, Budget, 149 846 TL no-return grant (approximately 24 500 Euros)

2017-2020 TUBITAK 1001,116F197, Investigation of Growth Behaviors and 2DEG Properties of of MgZnO/ZnO Heterostructures grown by USPECVD Method, PI, Budget, 359 810 TL (approximately 88 600 Euros)

2014-2016 Joint grant of Scientific and Technological Research Council of Turkey and RFBR of Russia, 113F364, Manipulation properties of two-dimensional electronic gas using insitu surface passivation of AlGaN/GaN heterostructures by molecular beam epitaxy, PI, Budget: 282 910 TL (approximately 97 500 Euros)

2012-2013 University Research Grant, 05-2012/13, Numerical optimization of MgxZn1-xO/ZnO and BexZn1-xO/ZnO based heterostructure transistors, PI, Budget: 14 889 TL (approximately 6 500 Euros)

2012-2013 University Research Grant, 05-2012/14, Investigation of the effects of transition metal palladium on electronical, structural and optical properties of graphene nanoribbons, PI, Budget: 14 955 TL (approximately 6 500 Euros)

*Project memberships*

2010-2012 TUBITAK 1002 Support Project, 209T051, MOVPE growth and characterization of epitaxial germanium for infrared photovoltaic and sensor applications, Researcher, Budget: 25k TL (approximately 11k Euros)

2009-2012 TUBITAK 1007 Research Project, 107A012, Researcher, Budget: 4.7 M TL (approximately 2M Euros)

2008-2012 Military Related Research Project, SAVS020, Scholar, Budget: 5.8M TL (approximately 2 5M Euros)

2008-2010 TUBITAK 1001 Research Project, 108T018, Epitaxial growth and characterization of infrared AlGaAs laser diode materials, Scholar, Budget: 358 400 TL (approximately 156k Euros)

2008-2010 TUBITAK (Turkey) – ANCS (Romania) Joint Research Project, TBAG-U/220 (107A584), Studies on synthesis and characterization of TiO2 thinfilm nanostructures which have applications in ecological physics, Scholar, Budget: 58k TL (approximately 25k Euros)

2006-2009 Military Related Research Project, SAVM005, Researcher, Budget: 4.7 M TL (approximately 2M Euros)

2006-2007 TUBITAK 1007 Research Project, 105A005, Scholar, Budget: 5.5M TL (approximately 2 4M Euros)

**PROFESSIONAL APPOINTMENTS**

2019-2020 Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm, Germany (3 months)

2018-cont. Full Professor, Department of Physics, Faculty of Science, Gazi University, Ankara Turkey

2013 Visiting Researcher, School of Computer Science and Electronics Engineering, University of Essex, Colchester, UK.

2011-2018 Associate Professor, Department of Physics, Faculty of Science, Gazi University, Ankara Turkey

2009-2011 Assistant Professor, Department of Physics, Faculty of Science and Arts, Gazi University, Ankara Turkey

2008-2009 Post-doctoral Researcher, Nanotechnology Research Center, Bilkent University, Ankara, Turkey [http://www.nanotam.bilkent.edu.tr](http://www.nanotam.bilkent.edu.tr/)

**RESEARCH EXPERIENCE**

2019-2020 Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm, Germany (3 months)

2013 Visiting Researcher, Department of Computing and Electronic Systems University of Essex, Colchester, UK (6 months)

2008-2009 Post-doctoral Researcher, Nanotechnology Research Center, Bilkent University, Ankara, Turkey [http://www.nanotam.bilkent.edu.tr](http://www.nanotam.bilkent.edu.tr/)

2007-2008 Research Student, Department of Computing and Electronic Systems University of Essex, Colchester, UK (6 months)

**TEACHING EXPERIENCE**

These courses correspond to a number of more than 2300 students as of this CV’s writing time.

*Institute of Science, Gazi University, Ankara, Turkey*

2020/1 Instructor, Fiz 5026 Physics of Low-dimensional Semiconductors

2020/1 Instructor, Fiz 5024 Micro and Nanofabrication Methods

2019/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2018/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2018/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2017/2 Instructor, Fiz 524 Physics of Low-dimensional Semiconductors

2017/1 Instructor, Fiz 524 Physics of Low-dimensional Semiconductors

2017/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2016/2 Instructor, Fiz 524 Physics of Low-dimensional Semiconductors

2016/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2016/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2015/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2015/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2014/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2014/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2013/2 Instructor, Fiz 522 Micro and Nanofabrication Methods

2013/2 Instructor, Fiz 524 Physics of Low-dimensional Semiconductors

2013/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

2013/1 Instructor, Fiz 524 Physics of Low-dimensional Semiconductors

2012/1 Instructor, Fiz 522 Micro and Nanofabrication Methods

*Faculty of Science, Gazi University, Ankara, Turkey*

2020/1 Instructor, Fiz 1123 Introduction to Nanotechnology

2018/1 Instructor, Fiz 123 Introduction to Nanotechnology

2017/1 Instructor, Fiz 123 Introduction to Nanotechnology

2016/1 Instructor, Fiz 123 Introduction to Nanotechnology

2015/1 Instructor, Fiz 123 Introduction to Nanotechnology

2014/2 Advisor, Fiz 414 Research Project

2014/1 Advisor, Fiz 413 Research Project

2014/1 Instructor, Fiz 123 Introduction to Nanotechnology

2013/1 Advisor, Fiz 413 Research Project

2012/1 Advisor, Fiz 413 Research Project (2 students)

2011/2 Instructor, Enf 102 Basic Computer Usage and Fortran Language (2 groups)

2011/2 Advisor, Fiz 414 Research Project

*Faculty of Science and Arts, Gazi University, Ankara, Turkey*

2018/2 Advisor, Fiz 414 Research Project

2018/1 Advisor, Fiz 413 Research Project

2011/1 Advisor, Fiz 413 Research Project

2009/2 Advisor, Fiz 414 Research Project (2 students)

2009/1 Advisor, Fiz 413 Research Project (2 students)

*Faculty of Engineering, Gazi University, Ankara, Turkey*

2016/2 Instructor, Fiz 104, Physics II (2 groups)

2015/2 Instructor, Fiz 104, Physics II (2 groups)

2014/2 Instructor, Fiz 104, Physics II (2 groups)

2013/2 Instructor, Fiz 104, Physics II (4 groups)

2013/1 Instructor, Fiz 103 Physics I (3 groups)

2012/1 Instructor, Fiz 103 Physics I (2 groups)

2011/2 Instructor, Fiz 156 Physics Lab. (Mechanics)

2011/2 Instructor, Fiz 104, Physics II (3 groups)

2011/1 Instructor, Fiz 103 Physics I (3 groups)

2009/2 Instructor, Fiz 156 Physics Lab. (Mechanics)

2009/2 Instructor, Fiz 104, Physics II (2 groups)

*Faculty of Dentistry, Gazi University, Ankara, Turkey*

2012/1 Instructor, Fzk 111 Physics.

*Faculty of Science at Polatlı, Gazi University, Polatlı, Ankara, Turkey*

2012/1 Instructor, Fiz 315 Properties of Matter.

*Faculty of Technology, Gazi University, Ankara, Turkey*

2020/1 Instructor, Fiz 103, Physics II (2 groups)

2019/2 Instructor, Fiz 104, Physics II (2 groups)

2018/2 Instructor, Fiz 104, Physics II

2017/2 Instructor, Fiz 104, Physics II

2014/1 Instructor, Fiz 101 Physics I (2 groups).

2011/1 Instructor, Fiz 101 Physics I.

*Faculty of Technical Education, Gazi University, Ankara, Turkey*

2011/1 Instructor, Fiz 101 Physics I.

2009/2 Instructor, Fiz 102 Physics II.

2009/1 Instructor, Fiz 101 Physics I (4 groups).

*Turkish Military Academy, National Defense University, Ankara, Turkey*

2018-2019 Instructor, Physics.

**PROFESSIONAL ACTIVITIES**

2019 Scientific Committee Member, VIII. ADIM Physics Days, 12-15 September, Bilecik, Turkey.

2018 Scientific Committee Member, VII. ADIM Physics Days, 23-25 May, Aydin, Turkey.

2017 Scientific Committee Member, VI. ADIM Physics Days, 19-21 July, Balikesir, Turkey.

2015 Scientific Committee Member, 1st International Conference on Organic Electronic Material Technologies (OEMT-2015) 25-28 March Elazig, Turkey.

2015 Scientific Committee Member, 2nd International Nanoscience and Nanotechnology for Next Generation (NaNoNG) 29-31 October Antalya, Turkey.

2011-2014 Member of board of management of the Photonics Research Center at Gazi University, Ankara, Turkey. [http://fotonik.gazi.edu.tr](http://fotonik.gazi.edu.tr/)

2004 Member of organizing group of 11th Condensed Matter Ankara Meeting at Gazi University, Ankara, Turkey.

**PROFESSIONAL SERVICES**

*Editorial Board Member*

- PLOS ONE *(SCI-indexed) (2013-2016, 2019-continue)*

- Advances in Condensed Matter Physics *(SCI-indexed) (2019-continue)*

- Advances in OptoElectronics *(ESCI-indexed) (2019)*

*Issue Editor (SCI-indexed) (2016)*

- Advances in Materials Science and Technology “Recent Progress in Group III-Nitride Electronic and Optoelectronic Devices”

*Reviewer (SCI-indexed) (PUBLONS:* [*https://publons.com/researcher/2891039/sefer-bora-lisesivdin/*](https://publons.com/researcher/2891039/sefer-bora-lisesivdin/)*)*

- Journal of Physics and Chemistry of Solids

- Journal of Physics D – Applied Physics,

- Semiconductor Science and Technology,

- Superlattices and Microstructures,

- Journal of Materials Science: Materials in Electronics

- Journal of Materials Science: Materials in Electronics

- Nanotechnology,

- Diamond and Related Materials,

- Applied Physics Letters,

- Physica E : Low-dimensional Systems and Nanostructures,

- Physica B : Condensed Matter,

- AIP Advances,

- Computational Materials Science,

- Synthetic Metals,

**PROFESSIONAL AFFILIATIONS**

2005-present **Senior Member**, IEEE (Institute of Electrical and Electronics Engineers)

2005-present **Senior Member**, IEEE Electron Devices Society

2006 Member, IEEE Communications Society

2006 Member, SPIE (Society of Photographic Instrumentation Engineers)

Member, Hacettepe University Alumni

**SEMINARS**

12/2014 “**Elektriksel Olarak Pompalanan Seyreltik Azotlu Dikey Kaviteli Yarıiletken Optik Yükselteç” Physics Department, Istanbul University, Istanbul, Turkey.**

05/2008 “AlGaN/GaN-temelli Yüksek Elektron Hareketliliğine Sahip Transistörlerin (HEMTs) Elektron ve Manyeto-iletim Özelliklerinin İncelenmesi (in Turkish)”, Department of Physics, Akdeniz University, Antalya, Turkey.

02/2008 “Investigation of 2DEG parameters in AlGaN/GaN based heterostructures using QMSA technique” Department of Computing and Electronic Systems, University of Essex, Colchester, UK.

**ATTENDED COURSES AND WORKSHOPS**

01/2006 I. Adaligeli, “Solid State Educational Workshop 2006.1 : The Theory of Spin Transport (1 Week)” Feza Gürsey Institute, Istanbul, Turkey.

01/2006 J. Schliemann, “Solid State Educational Workshop 2006.1 : Rashba and Spin-Hall Effects in Quantum Dots (1 Week)” Feza Gürsey Institute, Istanbul, Turkey.

01/2006 E.V. Sukhorukov, “Solid State Educational Workshop 2006.1 : The Physics of Quantum Shot Noise (1 Week)” Feza Gürsey Institute, Istanbul, Turkey.

03-04/2005 R. Gerhardts, “Solid State Educational Workshop 2004.3-2: Magnetotransport in low-dimensional systems (3 Weeks)”, Bilkent University, Ankara, Turkey.

**PUBLICATIONS**

*Cites and h-index*

|  |  |  |
| --- | --- | --- |
| Index name | Total cite | h-index |
| *Web of Science* | 778 | 15 |
| *Google Scholar* | 975 | 16 |

*Books and Book Chapters*

**2** S. B. Lisesivdin, B. Sarikavak-Lisesivdin, E. Ozbay “Chapter 18: The Effects of the Interaction of Transition Metals on the Electronic Properties of the Graphene Nanosheets and Nanoribbons” Graphene Science Handbook Vol.3, CRCPress, Taylor&Francis, (2016).

**1** E. L. Wolf, M. Medikonda, (Transl. eds: B. Sarikavak-Lisesivdin, S. B. Lisesivdin) “Nanoteknoloji Devrimini Anlamak” Nobel Press, (2014).

*SCI-Articles*

**72** F. Sonmez, S. Ardali, G. Atmaca, S.B. Lisesivdin, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras “The effect of passivation layer, doping and spacer layer on electron-longitudinal optical phonon momentum relaxation time in Al0.3Ga0.7N/AlN/GaN heterostructures” *Mater. Sci. Semicond. Process.* **122**, 105449 (2021).

**71** H. Hebal, Z. Koziol, S.B. Lisesivdin, R. Steed “General-purpose open-source 1D self-consistent Schrödinger-Poisson Solver: Aestimo 1D” *Comput. Mater. Sci.* **186**, 110015 (2021).

**70** B.Sarikavak-Lisesivdin, S.B.Lisesivdin, E.Ozbay, F.Jelezko “Structural parameters and electronic properties of 2D carbon allotrope: Graphene with a kagome lattice structure” *Chem. Phys. Lett.* **760**, 138006 (2020).

**69** E. Kutlu, P. Narin, A. Yildiz, S. B. Lisesivdin “Effects of Annealing under Different Atmospheres on Structural and Optical Properties of USCVD grown ZnO Nanostructures” *Mater. Sci. Eng. B* **254**, 114506 (2020).

**68** R. Ibrahem, P. Narin, S. B. Lisesivdin, E. Ozbay “Investigation of electronic and optical properties of wurtzite MgZnO using GGA + U formalism”, *Philos. Mag. Lett.* **99**, 424 (2019).

**67** P. Narin, J. M. All Abbas, G. Atmaca, E. Kutlu, S. B. Lisesivdin, E. Ozbay "Ab initio study of electronic properties of armchair graphene nanoribbons passivated with heavy metal elements" *Solid State Commun.* **296**, 8 (2019).

**66** P. Narin, E. Arslan, M. Ozturk, M. Ozturk, S. B. Lisesivdin, E. Ozbay "Scattering analysis of ultrathin barrier (< 7 nm) GaN-based heterostructures" *Appl. Phys. A: Mater. Sci. Process.* **125**, 278 (2019).

**65** J. M. All Abbas, P. Narin, E. Kutlu, S. B. Lisesivdin, E. Ozbay "Electronic properties of Zigzag ZnO nanoribbons with Hydrogen and Magnesium passivations" *Physica B* **556**, (2019).

**64** J.-H. Lee, J.-M. Ju, G. Atmaca, J.-G. Kim, S.-H. Kang, Y. S. Lee, S.-H. Lee, J.-W. Lim, H.-S. Kwon, S. B. Lisesivdin, J.-H. Lee “ High Figure-of-Merit (V2BR/RON) AlGaN/GaN Power HEMT With Periodically C-Doped GaN Buffer and AlGaN Back Barrier” *IEEE J. Electron Dev. Soc.* **6**, 1179 (2018).

**63** Ö. Ömeroğlu, E. Kutlu, P. Narin, S. B. Lisesivdin, E. Ozbay “Electronic Properties of Graphene Nanoribbons Doped with Zinc, Cadmium, Mercury Atoms” *Physica E* **104**, 124 (2018).

**62** G. Atmaca, P. Narin, E. Kutlu, T. V. Malin, V. G. Mansurov, K. S. Zhuravlev, S. B. Lisesivdin, E. Ozbay, “Negative Differential Resistance Observation and a New Fitting Model for Electron Drift Velocity in GaN-Based Heterostructures” *IEEE Trans. Electron Dev.* **65**, 950 (2018).

**61** P. Narin, E. Kutlu, G. Atmaca, A. Atilgan, A. Yildiz. S. B. Lisesivdin, “Structural and optical properties of hexagonal ZnO nanostructures grown by ultrasonic spray CVD” *Optik* **168**, 86 (2018).

**60** E. Kutlu, P. Narin, S. B. Lisesivdin, E. Ozbay “Electronic and optical properties of black phosphorus doped with Au, Sn and I atoms” *Philos. Mag.* **98**, 155 (2018).

**59** P. Narin, E. Kutlu, G. Atmaca, S. B. Lisesivdin, E. Ozbay “A ﬁrst principles investigation of the effect of aluminum, gallium and indium impurities on optical properties of β-Si3N4 structure” *Optik* **147**, 115 (2017).

**58** J. M. Al Abbas, P. Narin, G. Atmaca, E. Kutlu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin “The effect of doping in different layers on 2DEG for ultrathin-barrier AlN/GaN heterostructures” *Optoelectron. Adv. Mater.-Rapid Comm.* **11**, 328 (2017).

**57** J. M. All Abbas, G. Atmaca, P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin “A Comparative Study of AlGaN and InGaN Back-Barriers in Ultrathin-Barrier AlN/GaN Heterostructures” *J. Elec. Mater.* **46**, 5278 (2017).

**56** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay “Electronic structure of β-Si3N4 crystals with substitutional icosagen group impurities” J. Optoelectron. Adv. Mater. 19, 278 (2017).

**55** P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Özbay "Electronic properties of Li-doped zigzag graphene nanoribbons" *Physica E* **84**, 543 (2016).

**54** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Özbay "Effect of substitutional As impurity on electrical and optical properties of β−Si3N4 Structure" *Mater. Res. Bull.* **83**, 128 (2016).

**53** G. Atmaca, S. Ardali, E. Tiras, T. Malin, V. G. Mansurov, K. S. Zhuravlev, S. B. Lisesivdin "Scattering analysis of 2DEG mobility in undoped and dopedAlGaN/AlN/GaN heterostructures with an *in situ* Si3N4 passivation layer" *Solid-State Electron.* **118**, 12 (2016).

**52** I. Kara, Y. Sarikavak, S. B. Lisesivdin, M. Kasap "Evaluation of Morphological and Chemical Differences of Gunshot Residues in Different Ammunitions Using SEM/EDS Technique" *Environ. Foren.* **17,** 68 (2016)*.*

**51** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, S. B. Lisesivdin "Two Dimensional Electron Gas in a Hybrid GaN/InGaN/ZnO Heterostructure with Ultrathin InGaN Channel Layer" *Physica E* **79**, 67 (2016)*.*

**50** G. Atmaca, S. Ardali, P. Narin, E. Kutlu, S. B. Lisesivdin, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "Energy relaxation of hot electrons by LO phonon emission in AlGaN/AlN/GaN heterostructure with in situ Si3N4 passivation" *J. Alloys Compounds* **659**, 90 (2016).

**49** S. Ardali, G. Atmaca, S. B. Lisesivdin, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "The variation of temperature dependent carrier concentration and mobility in AlGaN/AlN/GaN heterostructure with SiN passivation" *Phys. Stat. Sol. B* **252**, 1960 (2015).

**48** B. Sarikavak-Lisesivdin, S. B. Lisesivdin, N. Balkan, G. Atmaca, P. Narin, H. Cakmak, E. Ozbay "Energy relaxation of electrons in InGaN quantum wells" *Metall. Mater. Trans. A* **46**, 1565 (2015).

**47** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, M. Kasap “Electron Transport Properties of Two Dimensional Electron Gas in BexZn1-xO/ZnO Heterostructures” *Philos. Mag.* **95**, 79 (2015).

**46** G. Atmaca, P. Tasli, G. Karakoc, E. Yazbahar and S. B. Lisesivdin “Numerical Investigation of the 2DEG Properties of AlGaN/AlN/GaN HEMT Structures with InGaN/GaN MQW Back-Barrier Structure” Physica E 65, 110 (2015).

**45** O. Donmez, F. Sarcan, S. B. Lisesivdin, M. P. Vaughan, A. Erol, M. Gunes, M. C. Arikan, J. Puustinen and M. Guina, "Analytic modeling of temperature dependence of 2D carrier mobility in as-grown and annealed GaInNAs/GaAs quantum well structures" *Semicond. Sci. Technol.* **29**, 125009 (2014).

**44** S. B. Lisesivdin, G. Atmaca, E. Arslan, S. Cakmakyapan, O. Kazar, S. Butun, Jawad-ul-Hassan, E. Janzén and E. Ozbay “Extraction and scattering analyses of 2D and bulk carriers in epitaxial graphene-on-SiC structure” *Physica E* **63**, 87 (2014).

**43** E. Arslan, S. Cakmakyapan, O. Kazar, S. Bütün, S. B. Lisesivdin, N. A. Cinel, G. Ertas, S. Ardali, E. Tiras, J. Ul-Hassan, E.Janzén and Ekmel Özbay “SiC substrate effects on electron transport in the epitaxial Graphene layer” *Electron. Mater. Lett.* **10**, 387 (2014).

**42** S. B. Lisesivdin, N. A. Khan, S. Mazzucato, N. Balkan, M. J. Adams, V.-M. Korpijärvi, M. Guina, G. Mezosi and M. Sorel “Optical gain in 1.3 μm electrically-driven dilute nitride VCSOAs” *Nanoscale Res. Lett.* **9**, 22 (2014).

**41** K. Elibol, G. Atmaca, P. Tasli, S. B. Lisesivdin “A Numerical Study on Subband Structure of InxAl1-xN/GaN-Based HEMT Structures with Low-Indium (x<0.10) Barrier Layer” *Solid State Commun.* **162**, 8 (2013).

#### 40 A. F. Kuloglu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay “First-principles calculations of Pd-terminated symmetrical armchair graphene nanoribbons” *Comp. Mater. Sci.* 68, 18 (2013).

#### 39 B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay “The Effect of InxGa1-xN Back-barriers on the Dislocation Densities in Al0.31Ga0.69N/AlN/GaN/ InxGa1-xN/GaN Heterostructures (0.05 ≤ x ≤ 0.14)” *Cur. Appl. Phys.* 13, 224 (2013).

**38** B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay “Ab initio study of Ru-terminated and Ru-doped armchair graphene nanoribbons” *Mol. Phys.* **110**, 2295 (2012).

**37** E. Tiras, O. Celik, S. Mutlu, S. Ardali, S. B. Lisesivdin, E. Ozbay “Temperature dependent energy relaxation time in AlGaN/AlN/GaN heterostructures” *Superlat. Microstruct.* **51**, 733 (2012).

**36** O. Celik, E. Tiras, S. Ardali, S. B. Lisesivdin, E. Ozbay “Determination of the LO phonon energy by using electronic and optical methods in AlGaN/GaN” *Cent. Eur. J. Phys.* **10**, 485 (2012).

**35** O. Kelekci, S. B. Lisesivdin, S.Ozcelik, E. Ozbay “Numerical optimization of In-mole fraction and layer thicknesses in AlxGa1-xN/AlN/GaN high electron mobility transistors with InGaN back barrier” *Physica B* **406**, 1513 (2011).

**34** A. Yildiz, P. Tasli, B. Sarikavak, S. B. Lisesivdin, M. K. Ozturk, M. Kasap, S. Ozcelik, E. Ozbay “Grain boundary related electrical transport in Al-rich AlxGa1-xN layers grown by metal organic chemical vapor deposition” *Semiconductors+* **45**, 33 (2011).

**33** H. Yu, S. B. Lisesivdin, B. Bolukbas, O. Kelekci, M. K. Ozturk, S. Ozcelik, D. Caliskan, M. Ozturk, H. Cakmak, P. Demirel ve E. Ozbay “Improvement of breakdown characteristics in AlGaN/GaN/AlxGa1−xN HEMT based on a grading AlxGa1−xN buffer layer” *Phys. Stat. Sol. a* **207**, 2593 (2010).

**32** P. Tasli, B. Sarikavak, G. Atmaca, K. Elibol, A. F. Kuloglu ve S. B. Lisesivdin “Numerical Simulation of Novel Ultrathin Barrier n-GaN/InAlN/AlN/GaN HEMT Structures: Effect of In Mole Fraction, Doping and Layer Thicknesses” *Physica B* **405**, 4020 (2010).

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**11** S. B. Lisesivdin, A. Yildiz, S. Acar, M. Kasap, S. Ozcelik, S. Gokden, E. Ozbay “Improved Scattering Analysis of 2DEG carriers in Al0.25Ga0.75N/GaN Heterostructures” *NanoTr3 Conference Proceedings*, p134 (2007).

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**8** A. Yildiz, S. B. Lisesivdin, S. Acar, and M. Kasap “Mole Fraction Dependence Of Mobility In InxGa1-xN Alloys” *AIP Conf. Proc.* **899** 670 (2007).

**7** S. B. Lisesivdin and M. Kasap “Simulation of the Interfacial AlN Layer on Band Structures and Carrier Densities of AlGaN/GaN HEMT Structures” *AIP Conf. Proc.* **899** 622 (2007).

**6** S. B. Lisesivdin, A. Yildiz, M. Kasap, and E. Ozbay “Strain Calculations from Hall Measurements in Undoped Al0.25Ga0.75N/GaN HEMT Structures” *AIP Conf. Proc.* **899** 623 (2007).

**5** S. B. Lisesivdin, S. Acar, M. Kasap “Transport properties of the 2DEG and minority carriers in AlGaN/GaN HEMT Structures grown by MOCVD” *XIII. Solid State Matter Physics Ankara Meeting*, **P-71**, p104 (2006).

**4** S. Acar, S. B. Lisesivdin, M. Kasap “Two dimensional hole gas (2DHG) formation evidence in AlGaN/GaN/AlN HEMTs” *XIII. Solid State Matter Physics Ankara Meeting*, **P-72**, p105 (2006).

**3** S. B. Lisesivdin, S. Acar, M. Kasap and S. Ozcelik “QMSA Analysis and Effects of Extreme Space-Charge Scattering on the Mobility in III-V Systems grown by MBE” *Turkish Physical Society XXIII. International Conference*, p1214 (2005).

**2** S. B. Lisesivdin, U. Yurdugul, S. Demirezen, S. Acar and M. Kasap “Galvanomagnetic measurements of LEC grown Te-doped InSb” *XI. Solid State Matter Physics Ankara Meeting*, **P-46**, p79 (2004).

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**ADVISING**

*PhD*

**3** E. Kutlu, (Ankara University, Institute of Science, Physics Engineering), *2018- present.* Second Advisor.

**2** P. Narin, (Gazi University, Institute of Science, Physics), *2015 - present*. Advisor.

**1** G. Atmaca, (Gazi University, Institute of Science, Physics), Investigations of Low-field Transport and Hot-electron Transport in Passivated AlGaN/GaN HEMTs with Si3N4 *2013 - 2018*. Advisor.

*MSc*

**12** K. B. Sönmez, (Gazi University, Institute of Science, Advanced Technologies), RF Magnetron Sputter System and Passive Circuit Element Resistor Production and Characterization *2016 - 2019*. Advisor.

**11** M. T. Haliloğlu, (Gazi University, Institute of Science, Advanced Technologies), Back Side Via Hole Etching Application of SiC for GaN-based Field Effect Transistors *2016 - 2019*. Advisor.

**10** O. Omeroglu, (Gazi University, Institute of Science, Physics), Investigation of the Electronic Properties of Zn, Cd and Hg-doped Graphene Sheets with Ab-Initio Methods, *2016 - 2018*. Advisor.

**9** R. Ibrahem, (Gazi University, Institute of Science, Physics), Investigation of Electronic and Optical Properties of Wurtzite MgZnO with First Principles Calculations, *2016 - 2018*. Advisor.

**8** M. Ozturk, (Gazi University, Institute of Science, Physics), Electrical Characteristics and Scattering Analysis of Ultrathin Barrier GaN-Based High Electron Mobility Transistors, *2015 - 2018*. Advisor.

**7** J. M. M. J. Al-Abbas, (Gazi University, Institute of Science, Physics),Simulation and optimation of GaN-based ultrathin barrier high electron mobility transistors, *2014 - 2016*. Advisor.

**6** E. Kutlu, (Gazi University, Institute of Science, Physics), Investigation of the effects of Cadmium Doping on Electronic and Optical Properties of Graphene Nanoribbons, *2014 -2016*. Advisor.

**5** A. F. Kuloglu, (Gazi University, Institute of Science, Physics), Investigation of Electronic Properties of Pa-terminated Graphene Nanoribbons, *2010-2012*. Advisor.

**4** G. Atmaca, (Gazi University, Institute of Science, Physics), Numerical Investigation of the 2-Dimensional Carriers in AlQN/AlN/GaN-Based (Q=Ga, In) Transistors with Multi-Quantum Well Back-Barriers, *2010-2012*. Advisor.

**3** K. Elibol, (Gazi University, Institute of Science, Physics), Investigation of Magnetoconductivity and Surface Properties of Exfoliated and Epitaxially Grown Graphene Samples, *2010-2012*. Advisor.

**2** G. Karakoc, (Gazi University, Institute of Science, Physics), Investigating the Electron Transport Properties of AlInN/AlN/(InGaN)/GaN Heterostructures with InGaN Quantum Wells. *2009-2012*. Advisor.

**1** C. Gunes, (Gazi University, Institute of Science, Physics), Electron and magnetotransport investigation of two dimensional electron gas in ultrathin barrier GaN-based heterostructures. *2009-2012*. Advisor.

**PERSONAL INFORMATION AND OTHER EXPERIENCE**

*Birth date*: September 12th, 1979

*Social Status*: Married and have a son.

2018-2020 CEO, Biarsis Ltd. Company manufacturing UV-Vis Spectrometers and light sources. Successful acquisition of company is completed at September 2020, <http://www.biarsis.com/>, Ankara, Turkey.

2010-2011 Completed the one-year full-time long military service as Assistant Professor Air Defence Second Lieutenant at Turkish Army Forces, 8. Corps, Air Defence Battalion which is located at Ercis, Van, Turkey.

-End of CV-

Last update: November 5th, 2020.

Hereby, I am confirming that all information listed on this CV is correct at this date.